

ORDERING INFORMATION

Temp. Range	Package	Standard Part Number	Lead (Pb)-free Part Number
- 40 °C to 85 °C	16-Pin Plastic DIP	DG221BDJ	DG221BDJ-E3
	16-Pin Narrow SOIC	DG221BDY DG221BDY-T1	DG221BDY-E3 DG221BDY-T1-E3

ABSOLUTE MAXIMUM RATINGS

Parameter	Limit	Unit
Voltages Referenced V+ to V-	34	V
GND	25	
Digital Inputs ^a , V _S , V _D	(V-) - 2 to (V+) + 2 or 20 mA, whichever occurs first	
Continuous Current (Any Terminal)	30	mA
Continuous Current, S or D	20	
Peak Current, S or D (Pulsed at 1 ms, 10 % duty cycle max.)	70	
Storage Temperature	(DJ and DY Suffix)	- 65 to 125 °C
Power Dissipation (Package) ^b	16-Pin Plastic DIP ^c	470 mW
	16-Pin SOIC ^d	600 mW

Notes:

- a. Signals on S_X, D_X, or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 6.5 mW/°C above 25 °C.
- d. Derate 7.7 mW/°C above 75 °C.

SCHEMATIC DIAGRAM Typical Channel

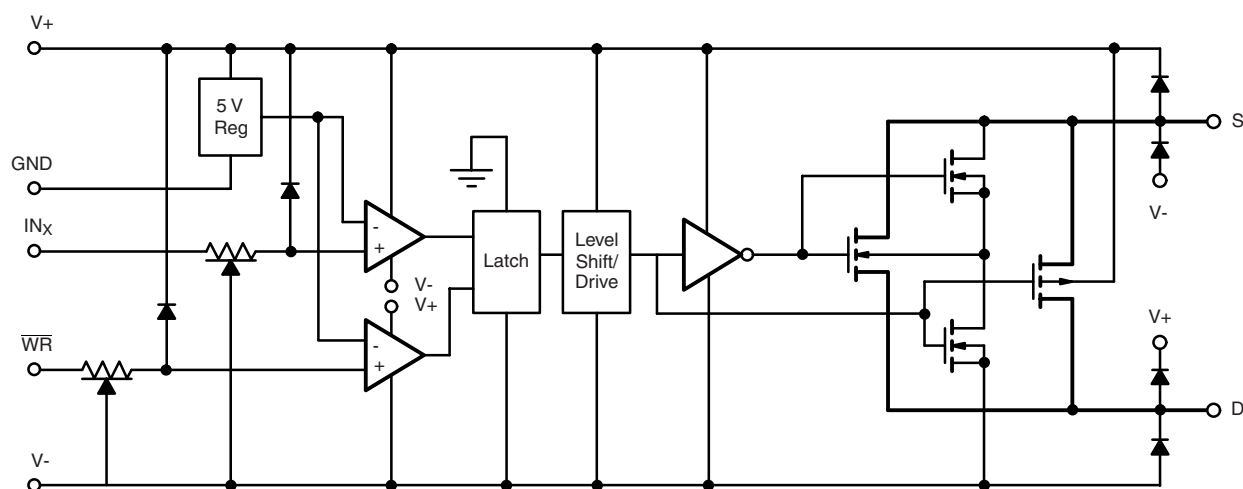


Figure 1.



SPECIFICATIONS ^a							
Parameter	Symbol	Test Conditions Unless Otherwise Specified V ₊ = 15 V, V ₋ = - 15 V V _{IN} = 2.4 V, 0.8 V ^f , \overline{WR} = 0	Temp. ^b	Limits - 40 °C to 85 °C			Unit
				Min. ^d	Typ. ^c	Max. ^d	
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	- 15		15	V
Drain-Source On-Resistance	r _{DS(on)}	I _S = - 10 mA, V _D = ± 10 V	Room Full		60	90 135	Ω
Source Off Leakage Current	I _{S(off)}	V _S = ± 14 V, V _D = ± 14 V	Room Full	- 5 - 100	± 0.01	5 100	nA
Drain Off Leakage Current	I _{D(off)}		Room Full	- 5 - 100	± 0.02	5 100	
Drain On Leakage Current	I _{D(on)}	V _S = V _D = ± 14 V	Room Full	- 5 - 200	± 0.01	5 200	
Digital Control							
Input Current	I _{INL} , I _{INH}	V _{IN} = 0 V or = 2.4 V	Room Full	- 1 - 10	- 0.0004	1 10	μA
Dynamic Characteristics							
Turn-On Time	t _{ON}	See Figure 2	Room			550	ns
Turn-Off Time	t _{OFF}		Room			340	
Turn-On Time Write	t _{ON} , \overline{WR}	See Figure 3	Room			550	
Turn-Off Time Write	t _{OFF} , \overline{WR}		Room			340	
Write Pulse Width	t _W	See Figure 4	Room	150	120		
Input Setup Time	t _S		Room	180	130		
Input Hold Time	t _H		Room	20	18		
Charge Injection	Q	C _L = 1000 pF, V _{gen} = 0 V, R _{gen} = 0 Ω	Room		20		pC
Source-Off Capacitance	C _{S(off)}	f = 1 MHz, V _S , V _D = 0 V	Room		8		pF
Drain-Off Capacitance	C _{D(off)}		Room		9		
Channel On Capacitance	C _{D(on)}		Room		29		
Off-Isolation	OIRR	V _S = 1 V _{p-p} , f = 100 kHz	Room		70		dB
Interchannel Crosstalk	X _{TALK}	C _L = 15 pF, R _L = 1 kΩ	Room		90		
Power Supplies							
Positive Supply Current	I ₊	All Channels On or Off V _{IN} = 0 V or 2.4 V	Full		0.8	1.5	mA
Negative Supply Current	I ₋		Room	- 1	- 0.4		

Notes:

- Refer to PROCESS OPTION FLOWCHART.
- Room = 25 °C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Guaranteed by design, not subject to production test.
- V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TEST CIRCUITS

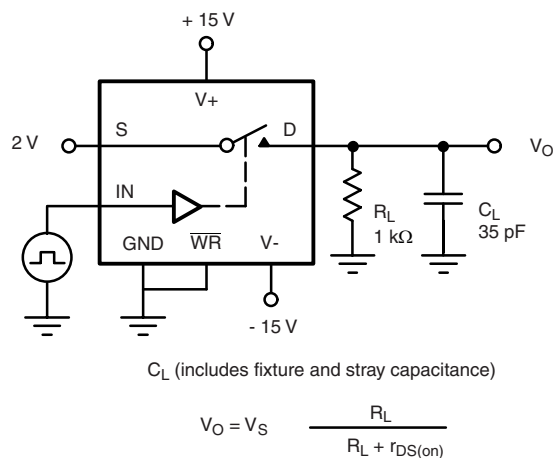


Figure 2. Switching Time

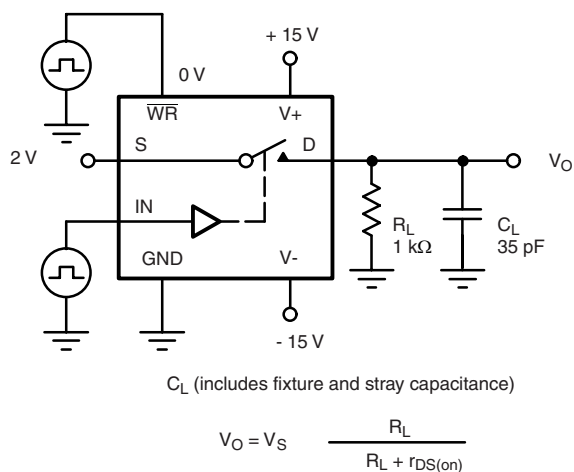
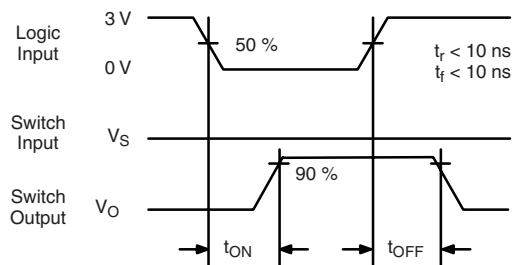


Figure 3. \overline{WR} Switching Time

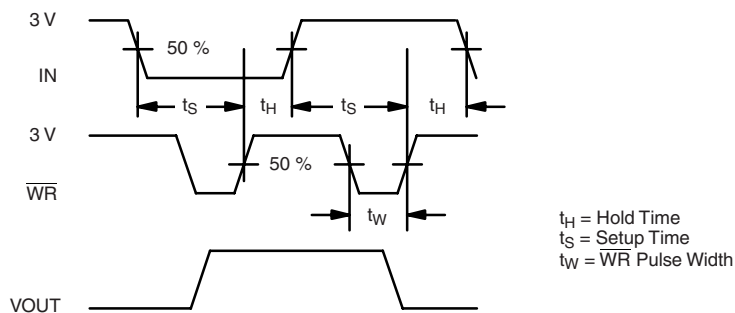
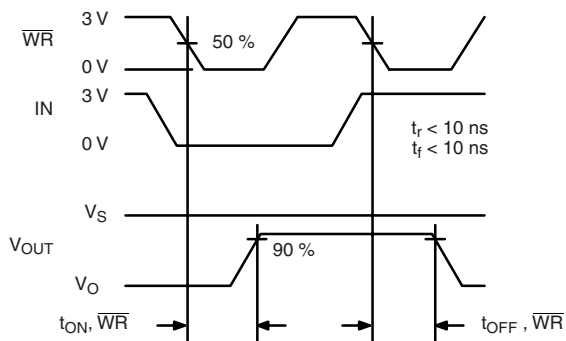
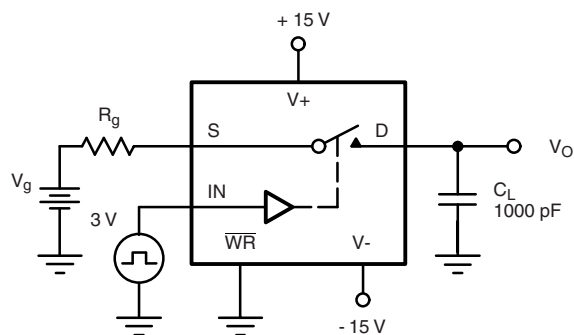
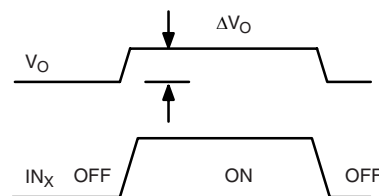
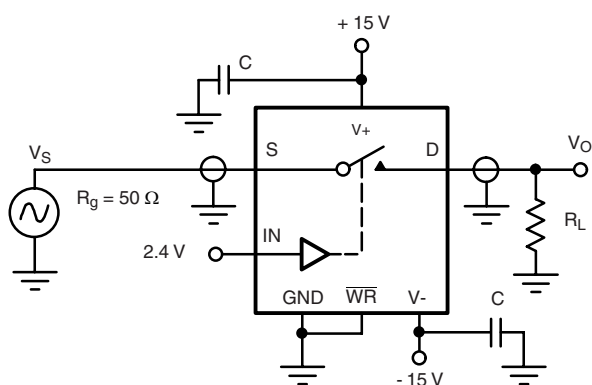


Figure 4. \overline{WR} Setup Conditions

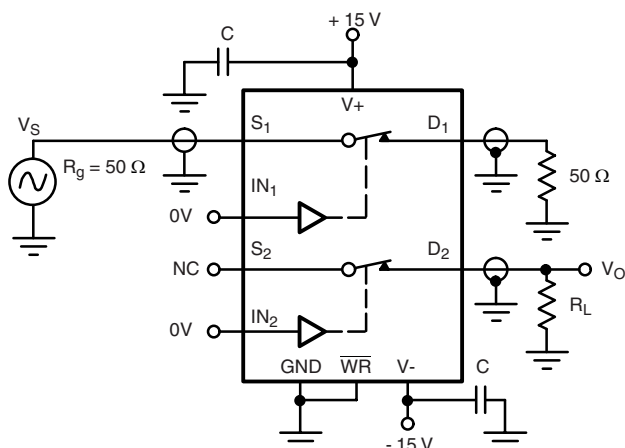
TEST CIRCUITS

Figure 5. Charge Injection


ΔV_O = measured voltage error due to charge injection
The charge injection in coulombs is $Q = C_L \times \Delta V_O$



$$\text{Off Isolation} = 20 \log \left| \frac{V_S}{V_O} \right|$$

C = RF bypass

Figure 6. Off Isolation


$$X_{\text{TALK}} \text{ Isolation} = 20 \log \left| \frac{V_S}{V_O} \right|$$

C = RF bypass

Figure 7. Channel-to-Channel Crosstalk
APPLICATION HINTS^a

V+ Positive Supply Voltage (V)	V- Negative Supply Voltage (V)	GND (V)	WR (V)	VIN Logic Input Voltage VINH(min)/VINL(max) (V)	VS or VD Analog Voltage Range (V)
15	- 15	0	2.4/0.8	2.4/0.8	- 15 to 15
10	- 10	0	2.4/0.8	2.4/0.8	- 10 to 10
10	- 5	0	2.4/0.8	2.4/0.8	- 5 to 10

Notes:

a. Application hints are for DESIGN AID ONLY, not guaranteed and not subject to production testing.

APPLICATIONS

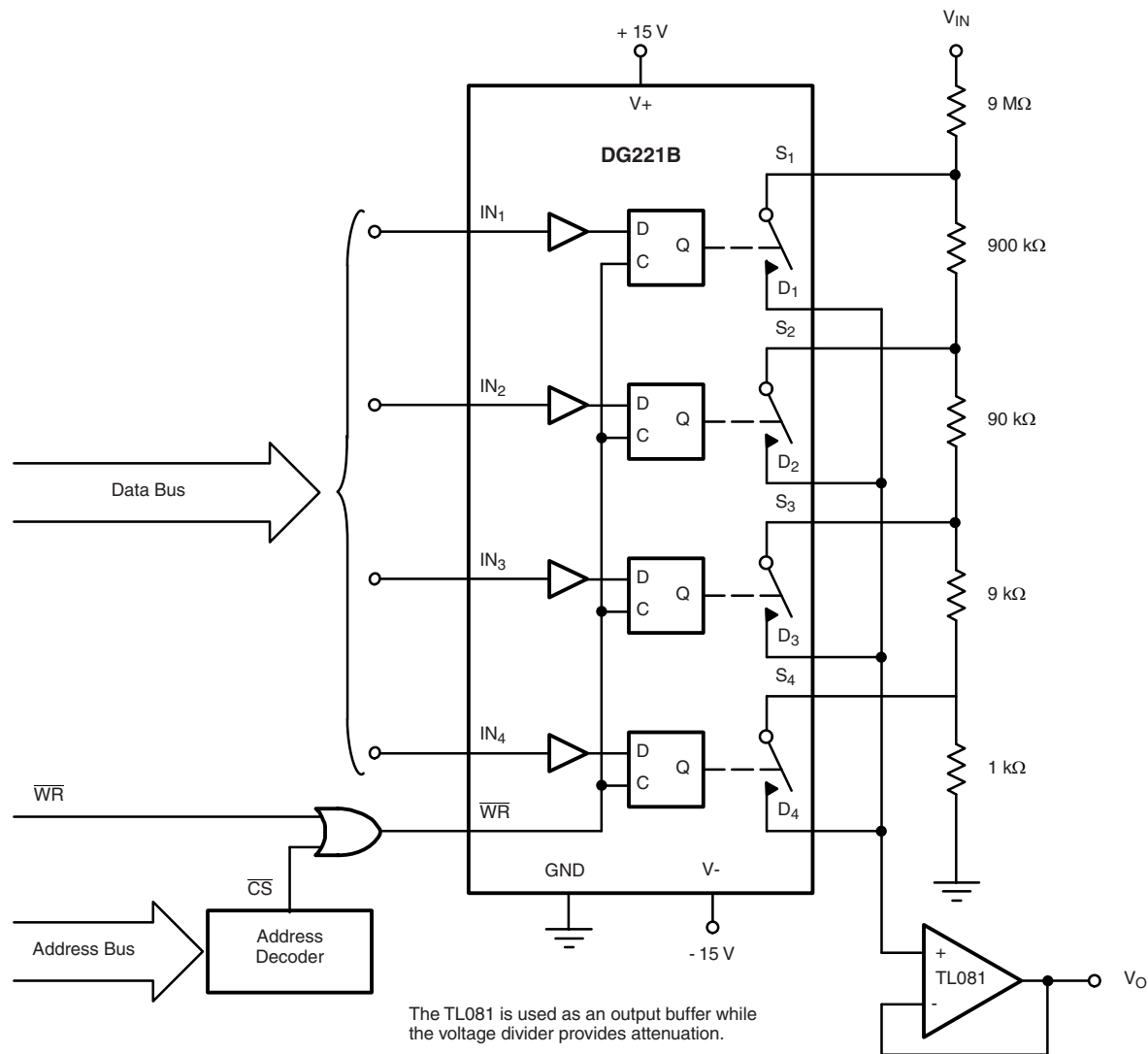


Figure 7. μ P-Controlled Analog Signal Attenuator

TRUTH TABLE					
IN ₁	IN ₂	IN ₃	IN ₄	\overline{WR}^a	ON SWITCH
0	0	0	0	0	All
1	1	1	1	0	None
0	1	1	1	0	1
1	0	1	1	0	2
1	1	0	1	0	3
1	1	1	0	0	4

Notes:

a. \overline{WR} may be held at "0" for temporary operation similar to DG201A/DG201B. With \overline{WR} at "0" SW₁ will remain on as long as IN₁ is held at "0" V.

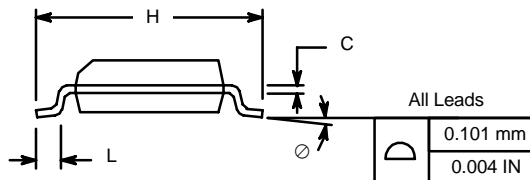
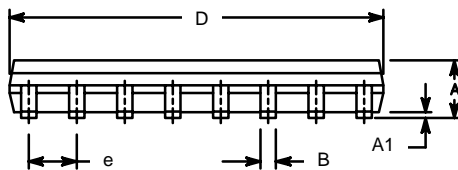
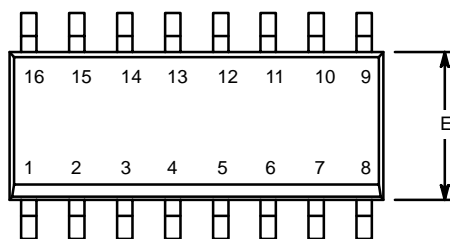
OUTPUT ATTENUATION FOR FIGURE 7					
\overline{WR}	IN ₁	IN ₂	IN ₃	IN ₄	Gain
0	0	1	1	1	0.1
0	1	0	1	1	0.01
0	1	1	0	1	0.001
0	1	1	1	0	0.0001

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SOIC (NARROW): 16-LEAD

JEDEC Part Number: MS-012

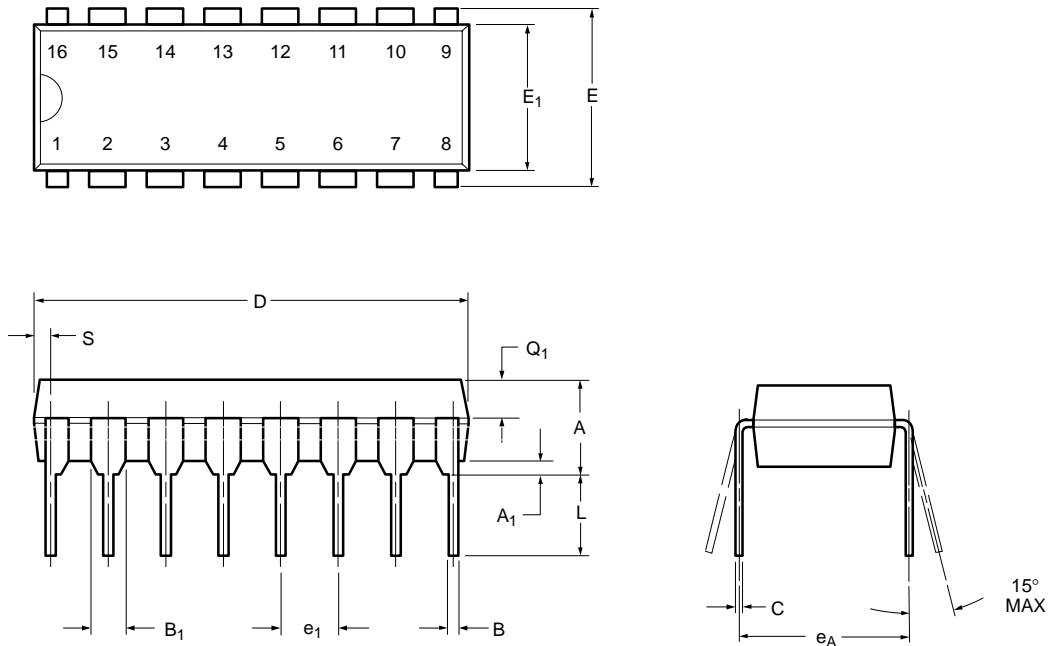


Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A ₁	0.10	0.20	0.004	0.008
B	0.38	0.51	0.015	0.020
C	0.18	0.23	0.007	0.009
D	9.80	10.00	0.385	0.393
E	3.80	4.00	0.149	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
L	0.50	0.93	0.020	0.037
⌀	0°	8°	0°	8°

ECN: S-03946—Rev. F, 09-Jul-01
DWG: 5300



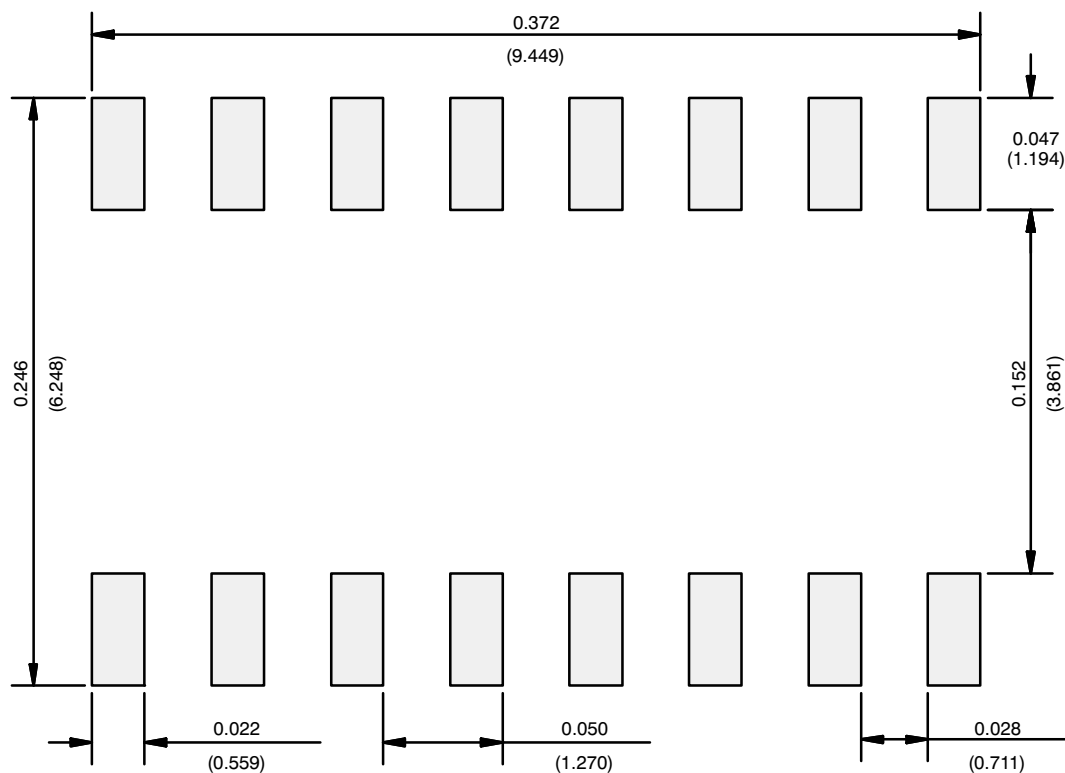
PDIP: 16-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	3.81	5.08	0.150	0.200
A ₁	0.38	1.27	0.015	0.050
B	0.38	0.51	0.015	0.020
B ₁	0.89	1.65	0.035	0.065
C	0.20	0.30	0.008	0.012
D	18.93	21.33	0.745	0.840
E	7.62	8.26	0.300	0.325
E ₁	5.59	7.11	0.220	0.280
e ₁	2.29	2.79	0.090	0.110
e _A	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
Q ₁	1.27	2.03	0.050	0.080
S	0.38	1.52	.015	0.060

ECN: S-03946—Rev. D, 09-Jul-01
DWG: 5482

RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads
Dimensions in Inches/(mm)

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